

# MBRS130LT3

## Schottky Power Rectifier

### Surface Mount Power Package

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

#### Features

- Very Low Forward Voltage Drop (0.395 Volts Max @ 1.0 A,  $T_j = 25^\circ\text{C}$ )
- Small Compact Surface Mountable Package with J-Bend Leads
- Highly Stable Oxide Passivated Junction
- Guard-Ring for Stress Protection
- Pb-Free Package is Available

#### Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 100 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes:  $260^\circ\text{C}$  Max. for 10 Seconds
- Cathode Polarity Band



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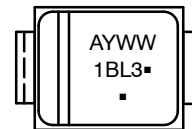
<http://onsemi.com>

**SCHOTTKY BARRIER  
RECTIFIER  
1.0 AMPERE  
30 VOLTS**



**SMB  
CASE 403A  
PLASTIC**

#### MARKING DIAGRAM



1BL3 = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping†
MBRS130LT3	SMB	2500/Tape & Reel
MBRS130LT3G	SMB (Pb-Free)	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MBRS130LT3

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	30	V
Average Rectified Forward Current $T_L = 120^\circ\text{C}$ $T_L = 110^\circ\text{C}$	$I_{F(AV)}$	1.0 2.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	$I_{FSM}$	40	A
Operating Junction Temperature	$T_J$	-65 to +125	$^\circ\text{C}$

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead	$\Psi_{JL}$	12	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient ( $T_A = 25^\circ\text{C}$ , Min Pad, 1 oz copper) Junction-to-Ambient ( $T_A = 25^\circ\text{C}$ , 1" Pad, 1 oz copper)	$R_{\theta JA}$	228.8 71.3	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 1.0\text{ A}$ , $T_J = 25^\circ\text{C}$ ) ( $i_F = 2.0\text{ A}$ , $T_J = 25^\circ\text{C}$ )	$V_F$	0.395 0.445	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_J = 25^\circ\text{C}$ ) (Rated dc Voltage, $T_J = 100^\circ\text{C}$ )	$I_R$	1.0 10	mA

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

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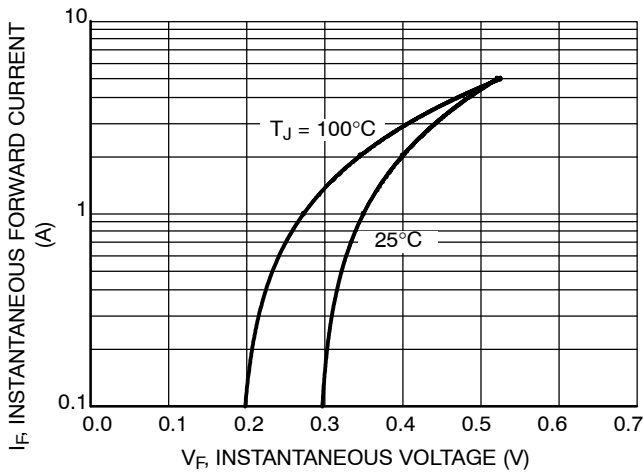


Figure 1. Typical Forward Voltage

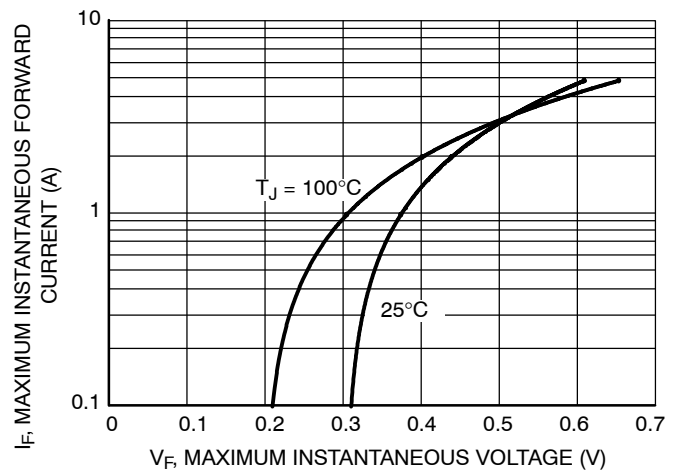


Figure 2. Maximum Forward Voltage

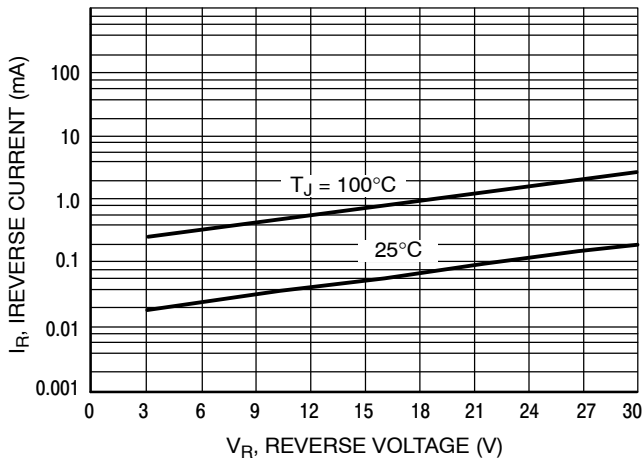


Figure 3. Typical Reverse Leakage Current

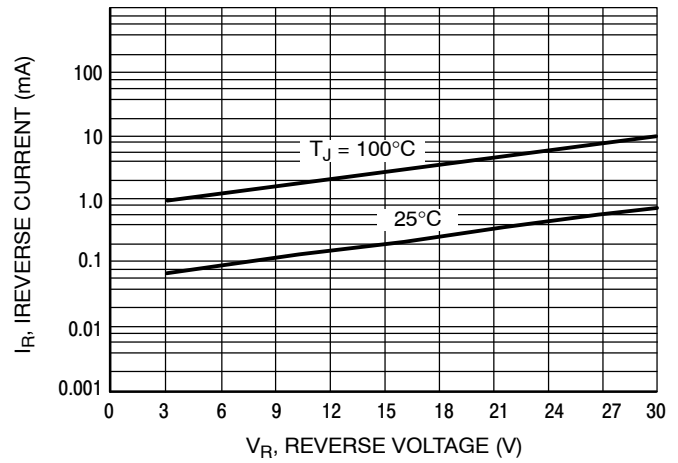


Figure 4. Typical Maximum Reverse Leakage Current

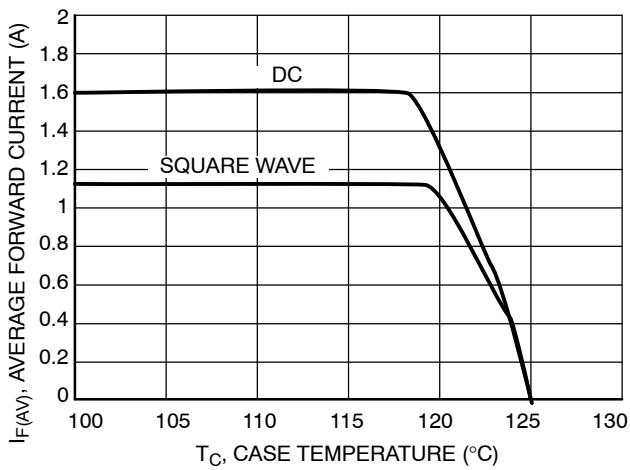


Figure 5. Current Derating (Case)

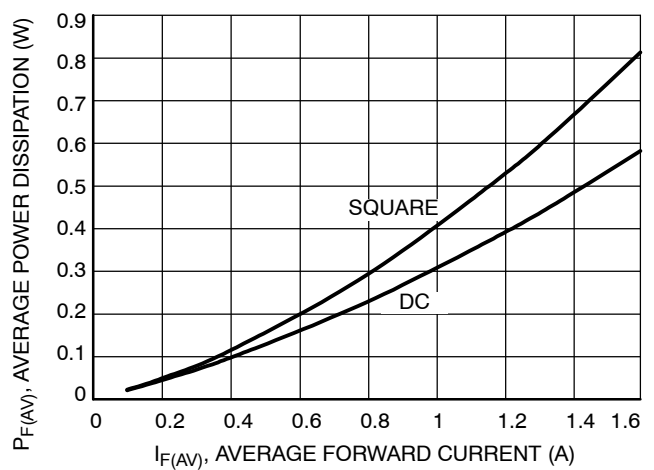


Figure 6. Typical Power Dissipation

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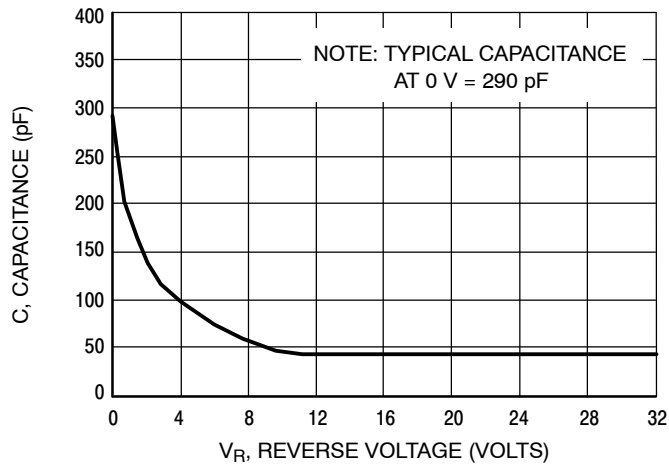


Figure 7. Typical Capacitance

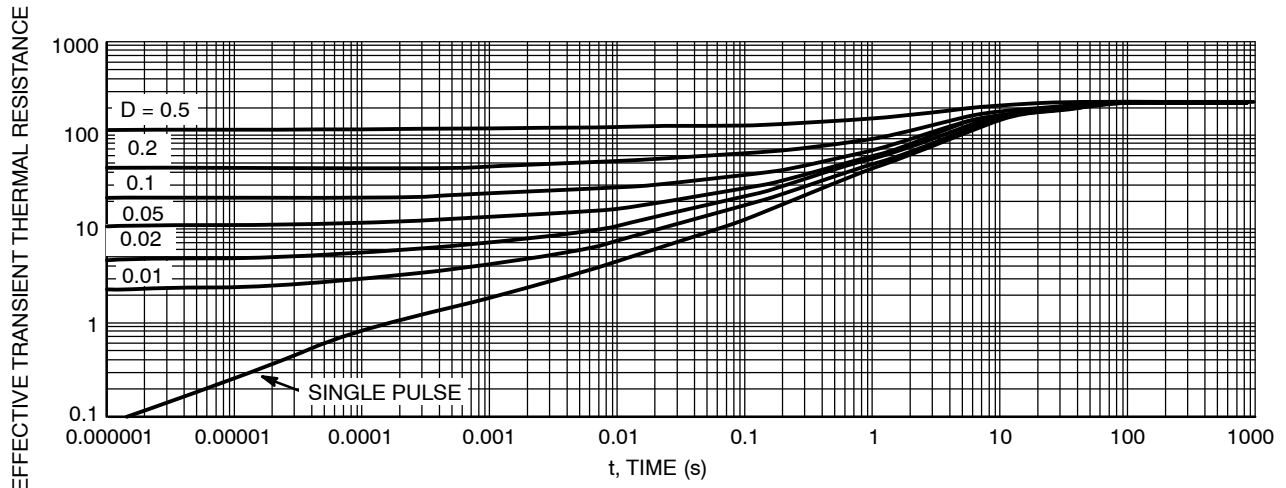


Figure 8. Thermal Response, Min Pad

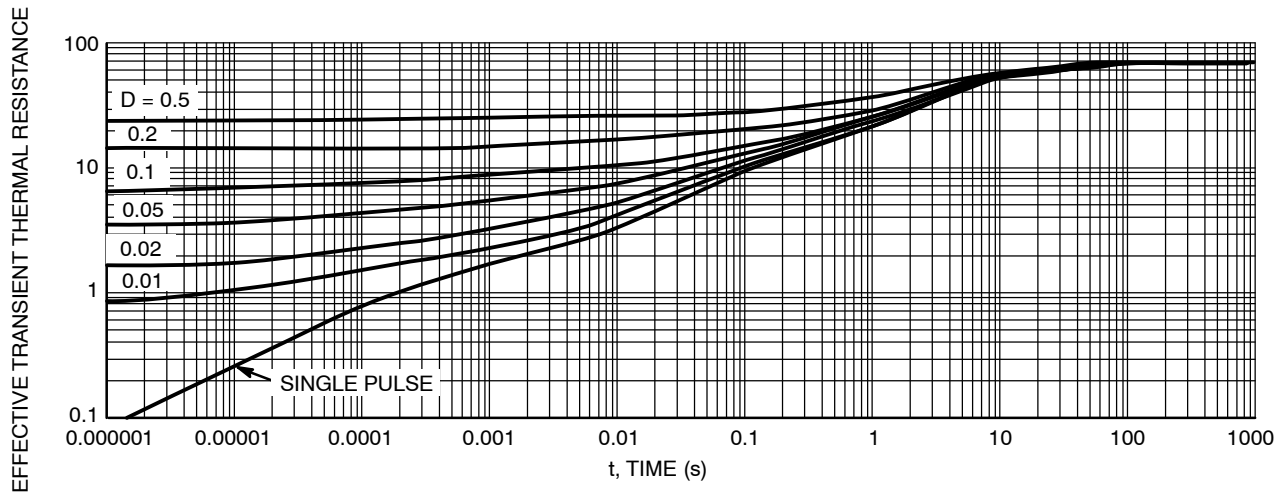
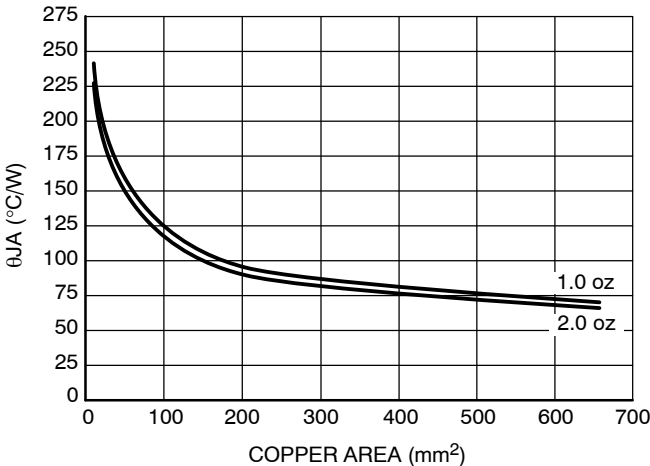
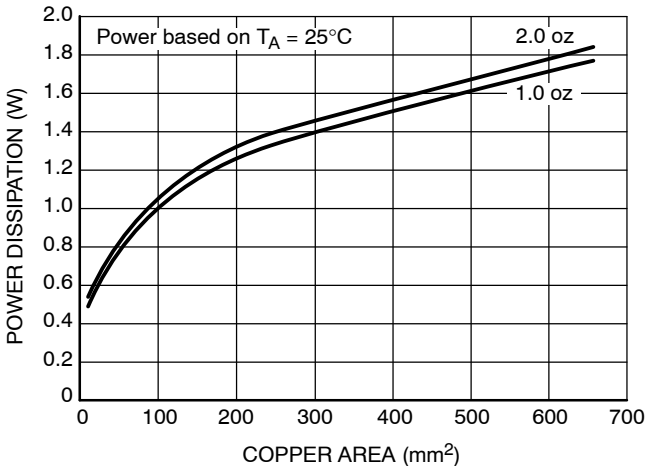


Figure 9. Thermal Response, 1 Inch Pad

**MBRS130LT3**



**Figure 10. Thermal Resistance vs. Copper Area**

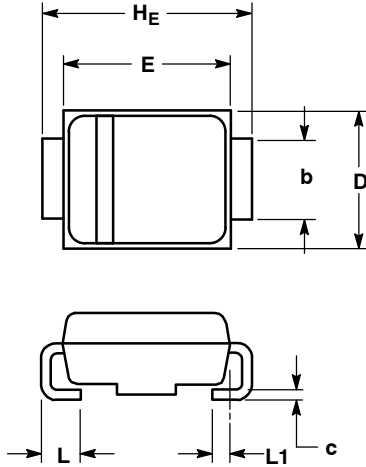


**Figure 11. Power Dissipation vs. Copper Area**

# MBR5130LT3

## PACKAGE DIMENSIONS

SMB  
CASE 403A-03  
ISSUE G

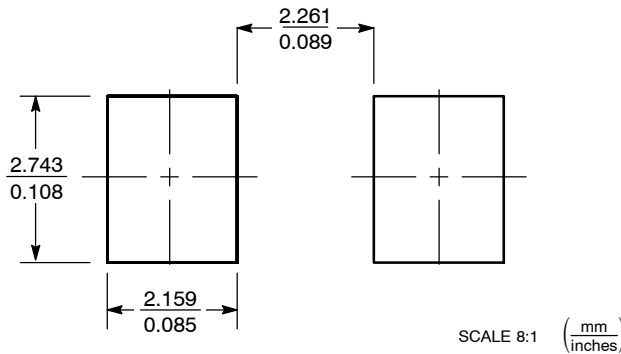


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.90	2.13	2.45	0.075	0.084	0.096
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.96	2.03	2.20	0.077	0.080	0.087
c	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
H <sub>E</sub>	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1	0.51 REF			0.020 REF		

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**MBRS130LT3/D**